

NOT RECOMMENDED FOR NEW DESIGN **CONTACT US**



DMN5L06VKQ

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BVDSS	R _{DS(ON)} Max	I _D Max T _A = +25°C
	2Ω @ V _{GS} = 5V	280mA
50V	2.5Ω @ V _{GS} = 2.5V	258mA
	3Ω @ V _{GS} = 1.8V	235mA

Description

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

General purpose interfacing switches

Features

- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.0V Max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMN5L06VKQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

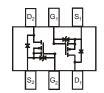
- Package: SOT563
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)

SOT563



ESD Protected up to 2kV





Internal Schematic

Ordering Information (Note 4)

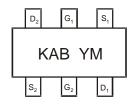
Part Number	Package	Packing			
Fait Number	rackaye	Qty.	Carrier		
DMN5L06VKQ-7	SOT563	3,000	Tape & Reel		
DMN5L06VKQ-13	SOT563	10,000	Tape & Reel		

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information (Note 5)



KAB = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022) M = Month (ex: 9 = September)

Date Code Key

Year	2014		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	В		J	K	L	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Note: 5. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain Source Voltage		V _{DSS}	50	V
Drain-Gate Voltage R _{GS} ≤ 1.0mΩ		VDGR	50	V
Gate-Source Voltage	Continuous Pulsed	Vgss	±20 ±40	V
Drain Current (Note 6)	Continuous	lo	280	mA
	Pulsed	Ірм	1.5	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	PD	250	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	500	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Note: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.





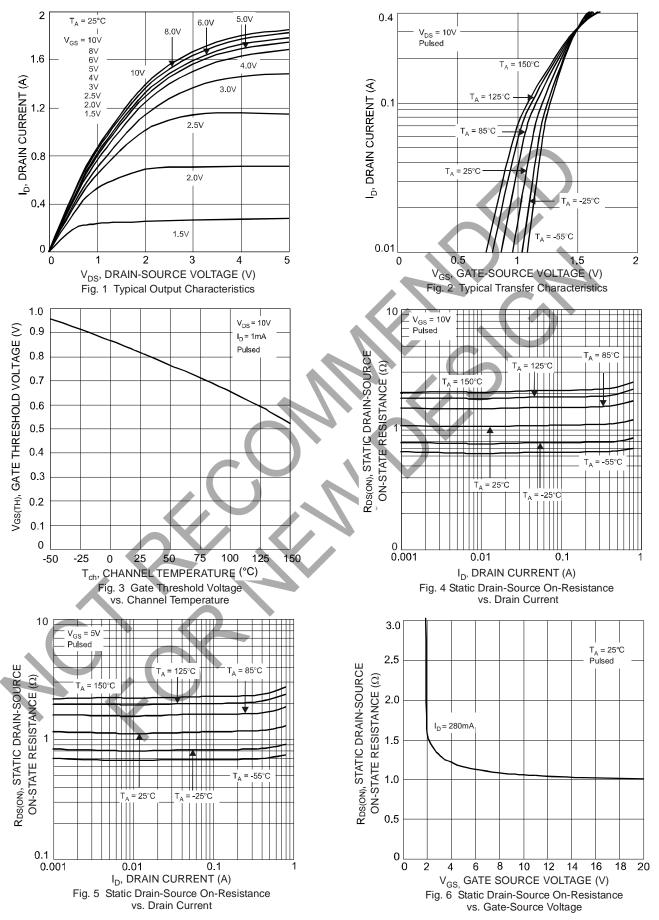
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage		BVDSS	50	_	_	>	$V_{GS} = 0V$, $I_D = 10\mu A$
Zero Gate Voltage Drain Current	@ T _C = +25°C	IDSS	_	_	60	nA	V _{DS} = 50V, V _{GS} = 0V
					1	μΑ	$V_{GS} = \pm 12V$, $V_{DS} = 0V$
Gate-Body Leakage		Igss	_	_	500	nA	$V_{GS} = \pm 10V$, $V_{DS} = 0V$
					50	nA	$V_{GS} = \pm 5V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	$@T_J = +25^{\circ}C$	Voortin	0.49		1.0	V	V _{DS} = V _{GS} , I _D = 250µA
@T _J =	0°C to +85°C (Note 8)	VGS(TH)	0.30	_	1.2	V	VDS = VGS, ID = 250μA
				2.49	3.0		$V_{GS} = 1.8V, I_{D} = 50mA$
Static Drain-Source On-Resistance		RDS(ON)		1.53	2.5	Ω	$V_{GS} = 2.5V, I_{D} = 50mA$
			_	1.16	2.0		$V_{GS} = 5.0V, I_{D} = 50mA$
On-State Drain Current		I _D (ON)	0.5	1.4		Α	$V_{GS} = 10V, V_{DS} = 7.5V$
Forward Transconductance		Y _{fs}	200	-		ms	$V_{DS} = 10V, I_{D} = 0.2A$
Source-Drain Diode Forward Voltage			0.5	0.73	1.4	٧	$V_{GS} = 0V$, $I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance		Ciss			50	pF	05)()(0)(
Output Capacitance		Coss	I - I	_	25	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance		Crss	1		5.0	pF	1 - 1.0WII IZ

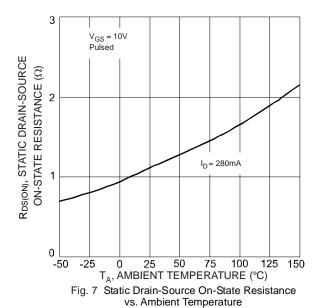
Notes:

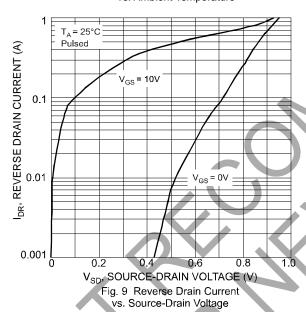
^{7.} Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to production testing.

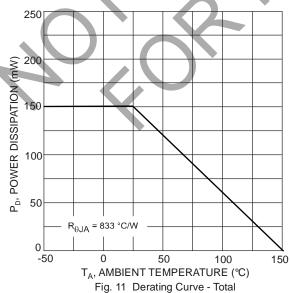












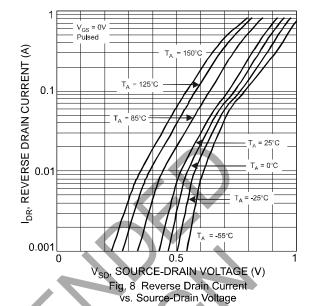


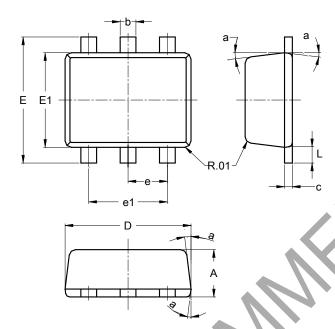
Fig.10 Forward Transfer Admittance vs. Drain Current



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563

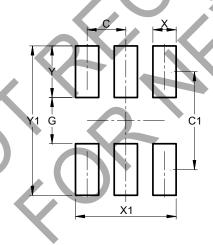


SOT563						
Dim	Min	Max	Тур			
Α	0.55	0.60	0.60			
b	0.15	0.30	0.20			
C	0.10	0.18	0.11			
ρ	1.50	1.70	1.60			
E	1.55	1.70	1.60			
E1	1.10	1.25	1.20			
e	ı	1	0.50			
e1	0.90	1.10	1.00			
L	0.10	0.30	0.20			
а	8°	9°	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563



Dimensions	SOT563
C	0.500
C1	1.270
O	0.600
X	0.300
X1	1.300
Υ	0.670
V1	1.040



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